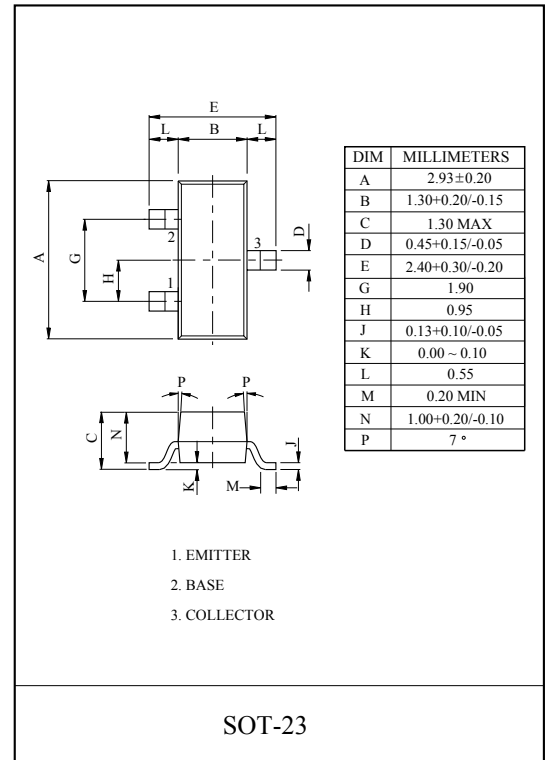


GENERAL PURPOSE APPLICATION.
DARLINGTON TRANSISTOR.

MAXIMUM RATING (Ta=25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	30	V
Collector-Emitter Voltage	V_{CES}	30	V
Emitter-Base Voltage	V_{EBO}	10	V
Collector Current	I_C	500	mA
Collector Power Dissipation	P_C^*	350	mW
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	-55 ~ 150	°C

* : Package Mounted On 99.5% Alumina 10×8×0.6mm.



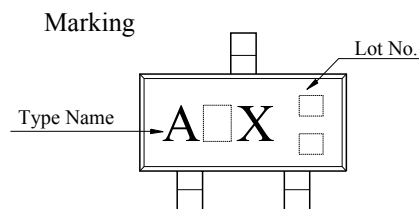
ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector-Emitter Breakdown Voltage	V_{CES}	$I_C=0.1mA$	30	-	-	V
Emitter Cut-off Current	I_{CBO}	$V_{CB}=30V$	-	-	100	nA
Emitter Cut-off Current	I_{EBO}	$V_{EB}=10V$	-	-	100	nA
DC Current Gain	MMBTA13	$I_C=10mA, V_{CE}=5V$	5,000	-	-	-
	MMBTA14		10,000	-	-	
	MMBTA13	$I_C=100mA, V_{CE}=5V$	10,000	-	-	
	MMBTA14		20,000	-	-	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=100mA, I_B=0.1mA$	-	-	1.5	V
Base-Emitter Voltage	V_{BE}	$I_C=100mA, V_{CE}=5V$	-	-	2.0	V
Current Gain Bandwidth Product	f_T	$I_C=10mA, f=100MHz, V_{CE}=5V$	125	-	-	MHz

*Pulse Test : Pulse Width ≤ 300μS, Duty Cycle ≤ 2.0%

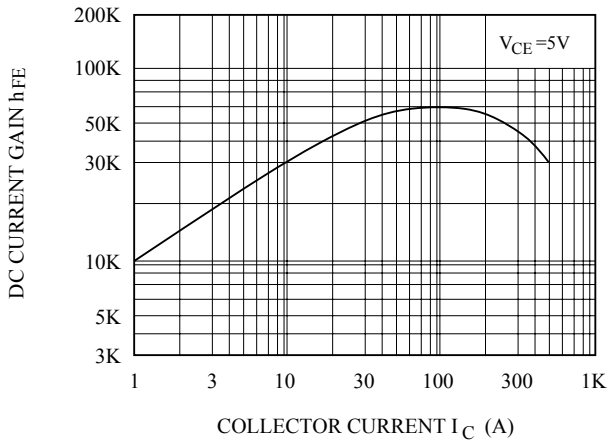
MARK SPEC

TYPE	MMBTA13	MMBTA14
MARK	AIX	AHX

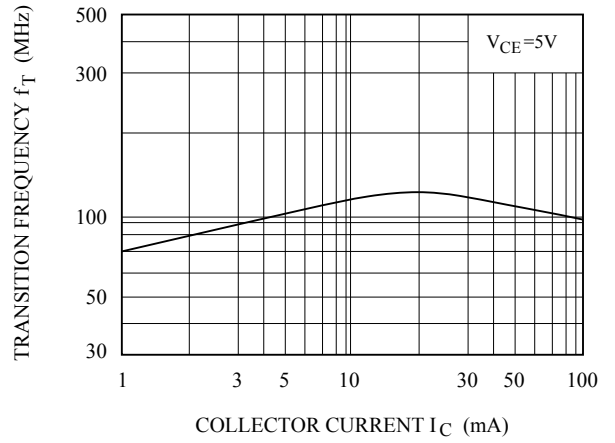


MMBTA13/14

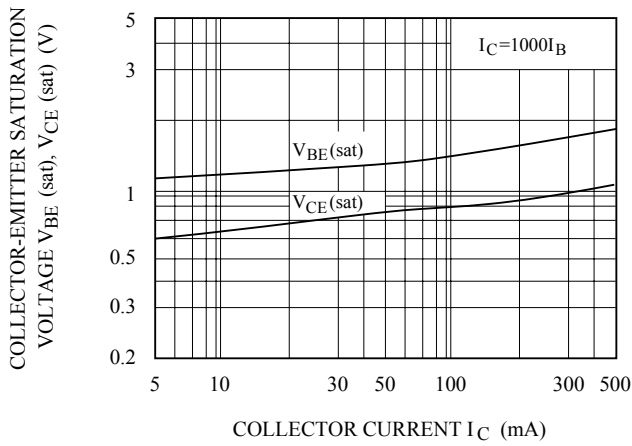
$h_{FE} - I_C$



$f_T - I_C$



$V_{BE} (sat), V_{CE} (sat) - I_C$



$I_C - V_{BE}$

